Darlington Transistors NPN Silicon

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	V _{CES}	30	Vdc	
Collector–Base Voltage	V _{CBO}	30	Vdc	
Emitter-Base Voltage	Voltage V _{EBO}		Vdc	
Collector Current — Continuous	Ι _C	500	mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

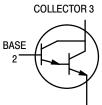


*ON Semiconductor Preferred Device



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	R_{\thetaJA}	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



EMITTER 1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage $(I_C = 100 \ \mu Adc, I_B = 0)$	V _{(BR)CES}	30	—	Vdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	I _{CBO}	—	100	nAdc
Emitter Cutoff Current (V_{EB} = 10 Vdc, I_C = 0)	I _{EBO}	—	100	nAdc

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit	
ON CHARACTERISTICS ⁽¹⁾						
DC Current Gain		h _{FE}			_	
(I _C = 10 mAdc, V _{CE} = 5.0 Vdc)	MPSA13		5,000			
	MPSA14		10,000	—		
(I _C = 100 mAdc, V _{CE} = 5.0 Vdc)	MPSA13		10,000	_		
	MPSA14		20,000	—		
Collector–Emitter Saturation Voltage ($I_C = 100 \text{ mAdc}, I_B = 0.1 \text{ mAdc}$)		V _{CE(sat)}	—	1.5	Vdc	
Base–Emitter On Voltage (I _C = 100 mAdc, V _{CE} = 5.0 Vdc)		V _{BE(on)}	-	2.0	Vdc	

Current–Gain – Bandwidth Product⁽²⁾ f_T 125MHz $(I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz})$ MHz

1. Pulse Test: Pulse Width \leq 300 µs; Duty Cycle \leq 2.0%.

2. $f_T = |h_{fe}| \cdot f_{test}$.

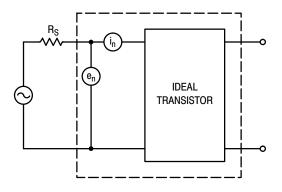


Figure 1. Transistor Noise Model

NOISE CHARACTERISTICS

 $(V_{CE}=5.0~Vdc,~T_{A}=25^{\circ}C)$

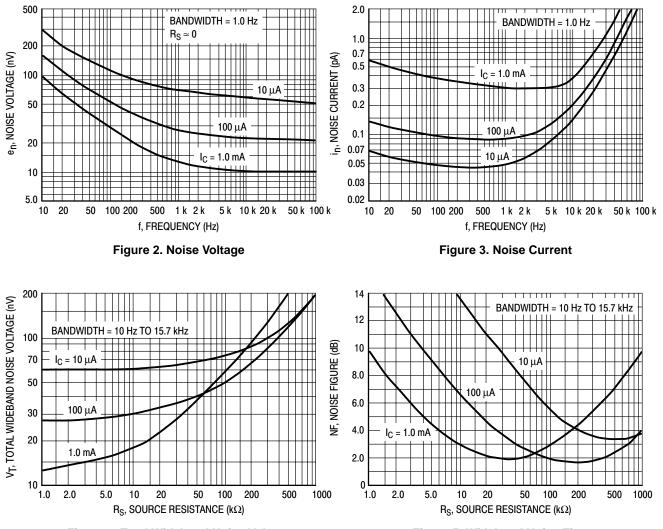
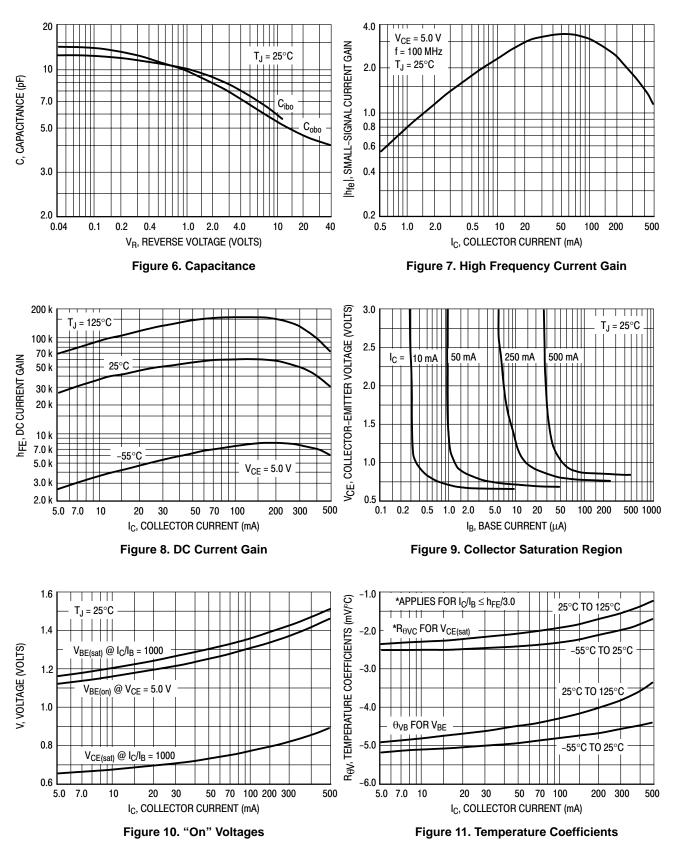
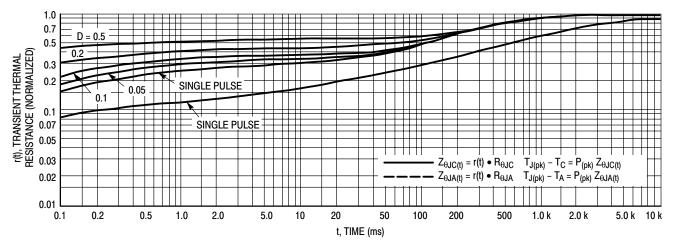


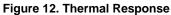
Figure 4. Total Wideband Noise Voltage

Figure 5. Wideband Noise Figure









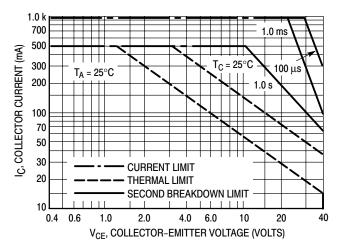
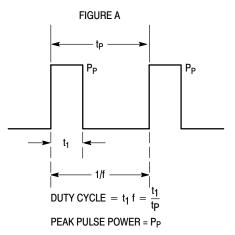


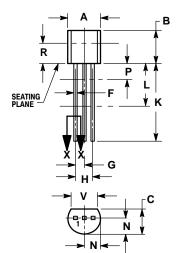
Figure 13. Active Region Safe Operating Area



Design Note: Use of Transient Thermal Resistance Data

PACKAGE DIMENSIONS

CASE 029-04 (TO-226AA) ISSUE AD





SECTION X-X

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. DIMENSION F APPLIES BETWEEN I AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

<u>Notes</u>

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